

Application/Control Number: 09/613,541

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1. (Amended) A semiconductor device comprising:

- (a) a rigid substrate, formed by glass fibers impregnated with epoxy resin, having a first main surface and a second main surface opposite to the first main surface;
- (b) a semiconductor pellet mounted on the first main surface of the rigid substrate, the semiconductor pellet having a plurality of semiconductor circuit elements and a plurality of bonding pads;
- (c) a plurality of electrode pads formed on the second main surface of the rigid substrate; and
- (d) a plurality of bonding wires for electrically connecting the bonding pads of the semiconductor pellet with the electrode pads;

wherein the semiconductor pellet is mounted facedown on the rigid substrate, the rigid substrate has slits that extend from the first main surface to the second main surface and expose the bonding pads of the semiconductor pellet, the bonding wires extend through the slits in the rigid substrate to connect the bonding pads and the electrode pads, and bump electrodes are formed on said electrode pads.

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**2. A semiconductor device according to claim 1, wherein the bonding pads are arranged at the periphery of the semiconductor pellet and the slits are formed along the directions of rows of the bonding pads.**

**3. A semiconductor device according to claim 2, wherein the electrode pads are located on both sides of the slits.**

**4. A semiconductor device according to claim 3, wherein the electrode pads located on one side of the slits and under the semiconductor pellet are power supply pads, and the electrode pads located on the other side of the slits and outside the semiconductor pellet are signal pads.**

**5. A semiconductor device according to claim 1, further comprising a first resin sealing body covering the semiconductor pellet.**

**6. A semiconductor device according to claim 5, further comprising a second resin sealing body formed in the slits and covering the bonding wires.**

7. (CANCELLED)

8. (CANCELLED)

9. (CANCELLED)

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10. (Twice Amended) A semiconductor device [according to claim 10.] comprising:

- (a) a rigid substrate having a first main surface and a second main surface opposite to the first main surface;
- (b) a semiconductor pellet mounted on the first main surface of the rigid substrate, the semiconductor pellet having a plurality of semiconductor circuit elements and a plurality of bonding pads;
- (c) a plurality of electrode pads formed on the second main surface of the rigid substrate; and
- (d) a plurality of bonding wires for electrically connecting the bonding pads of the semiconductor pellet with the electrode pads;

wherein the semiconductor pellet is mounted facedown on the rigid substrate, the rigid substrate has slits that extend from the first main surface to the second main surface and expose the bonding pads of the semiconductor pellet, the bonding wires extend through the slits in the rigid substrate to connect the bonding pads and the electrode pads, and bump electrodes are formed on said electrode pads;

wherein said rigid substrate is formed by glass fibers impregnated with polyimide resin.

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11. (Amended) A semiconductor device comprising:

- (a) a rigid substrate, formed by glass fibers impregnated with epoxy resin, having a first main surface and a second main surface opposite to the first main surface;
- (b) a semiconductor pellet mounted on the first main surface of the rigid substrate, the semiconductor pellet having a plurality of semiconductor circuit elements and a plurality of bonding pads;
- (c) a plurality of electrode pads formed on the second main surface of the rigid substrate; and
- (d) a plurality of bonding wires for electrically connecting the bonding pads of the semiconductor pellet with the electrode pads;

wherein the semiconductor pellet is mounted facedown on the rigid substrate, the rigid substrate has slits that extend from the first main surface to the second main surface and expose the bonding pads of the semiconductor pellet, and the bonding wires extend through the slits in the rigid substrate to connect the bonding pads and the electrode pads;

wherein the bonding pads are arranged at the periphery of the semiconductor pellet and the slits are formed along the directions of rows of the bonding pads.

**12. A semiconductor device according to claim 11, wherein the electrode pads are located on both sides of the slits.**

**13. A semiconductor device according to claim 12, wherein the electrode pads located on one side of the slits and under the semiconductor pellet are power supply pads, and the electrode pads located on the other side of the slits and outside the semiconductor pellet are signal pads.**

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14. (Amended) A semiconductor device comprising:

a substrate, formed by glass fibers impregnated with epoxy resin, of a quadrilateral shape having a first pair of opposed edges and a second pair of opposed edges, said substrate having a first main surface, a second main surface opposite to said first main surface and a first slit and a second slit each extending from said first main surface to said second main surface, said first slit extending along one of said first pair of opposed edges, said second slit extending along the other of said first pair of opposed edges, said substrate having first electrode pads on said second main surface in a first area between said first and second slits, second electrode pads on said second main surface in a second area between said first slit and said one of the first pair of opposed edges, and third electrode pads on said second main surface in a third area between said second slit and the other of the first pair of opposed edges;

a semiconductor pellet having a main surface with semiconductor elements and bonding pads said semiconductor pellet being mounted on said first main surface of substrate such that said bonding pads are arranged to be in line with said first and second slits;

bonding wires extending through said first and second slits in said substrate and electrically connecting said bonding pads and said first to third electrode pads, respectively;

a resin member sealing said semiconductor pellet and said bonding wires; and

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bump electrodes arranged on said second main surface of said substrate in said first to third areas in a direction of said first pair of opposed edges and being electrically connected with said first to third electrode pads, wherein said bump electrodes in said second and third areas are arranged to form plural rows in a direction of at least one of said second pair of opposed edges, respectively.

**15. A semiconductor device according to claim 14, wherein said semiconductor pellet has a quadrilateral shape and has a third pair of opposed edges and a fourth pair of opposed edges, wherein said bonding pads are arranged in a peripheral portion of said main surface and extend along said third pair of opposed edges.**

**16. A semiconductor device according to claim 15, wherein said semiconductor pellet is mounted on said first main surface opposite to said first area, wherein said substrate has a larger size than that of said semiconductor pellet, and wherein said bump electrodes in said second and third areas are located outside said third pair of opposed edges.**

**17. A semiconductor device according to claim 14, wherein the number of said bump electrodes in said second and third areas is larger than the number of said bump electrodes in said first area.**

**18. A semiconductor device according to claim 14, wherein said semiconductor pellet has a rear surface opposite to said main surface, and wherein said rear surface of said semiconductor pellet is exposed from said resin member.**

**19. A semiconductor device according to claim 14, wherein the number of said bump electrodes in said second area is larger than the number of said bump electrodes in said first area.**

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20. A semiconductor device according to claim [14] 16, wherein said semiconductor pellet has a rear surface opposite to said main surface, and wherein said rear surface of said semiconductor pellet is exposed from said resin member.

21. A semiconductor device according to claim 14, wherein said first electrode pads extend along said first and second slits, respectively, said second electrode pads extend along said first slit, and said third electrode pads extend along said second slit, wherein said first to third electrode

pads are arranged at a first pitch, respectively, wherein said bonding pads in said first and second slits are arranged at a second pitch which is smaller than said first pitch, respectively, wherein said bonding wires in said first slit alternately connect said bonding pads in said first slit with said first and second electrode pads, and wherein said bonding wires in said second slit alternately connect said bonding pads in said second slit with said first and third electrode pads.



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22. (Amended) A semiconductor device comprising:

a substrate, formed by glass fibers impregnated with epoxy resin, of a quadrilateral shape having first to fourth edges, said substrate having a first main surface, a second main surface opposite to said first main surface and first to fourth slits extending from said first main surface to said second main surface, said first to fourth slits respectively extending along said first to fourth edges and defining a first area of said substrate surrounded by said first to fourth slits and a second area of said substrate extending outside said first to fourth slits, said substrate having first electrode pads on said second main surface in said first area and second electrode pads on said second main surface in said second area;

a semiconductor pellet having a main surface with semiconductor elements and bonding pads, said semiconductor pellet being mounted on said first main surface of substrate such that said bonding pads are arranged in line with said first to fourth slits;

bonding wires extending through said first to fourth slits in said substrate and electrically connecting said bonding pads and said first and second electrode pads, respectively;

a resin member sealing said semiconductor pellet and said bonding wires; and bump electrodes arranged on said second main surface of said substrate in said first and second areas and being electrically connected with said first and second electrode pads,

wherein said bump electrodes in said second area are arranged to form a plurality of rows such that said plurality of rows are formed relative to one another to surround said first area of substrate.

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23. A semiconductor device according to claim 22, wherein said semiconductor pellet has a quadrilateral shape and has first to fourth edges, wherein said bonding pads are arranged in a peripheral portion of said main surface and extend along said first to fourth edges of said semiconductor pellet.

24. A semiconductor device according to claim 23, wherein said semiconductor pellet is mounted on said first main surface opposite to said first area, wherein said substrate has a larger size than that of said semiconductor pellet, and wherein said bump electrodes in said second area are located outside said first to fourth edges of said semiconductor pellet.

25. A semiconductor device according to claim 22, wherein said first and second electrode pads extending along said first to fourth slits, respectively, and are arranged at a first pitch, wherein said bonding pads extend along said first and second electrode pads and are arranged at a second pitch which is smaller than said first pitch, and wherein said bonding wires alternately connect said bonding pads with said first and second electrode pads.

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26. (Twice Amended) A semiconductor device comprising:

- (1) a semiconductor pellet of a quadrilateral shape having bonding pads formed in a main surface thereof, said semiconductor pellet having a first pair of opposed edges extending in a first direction and a second pair of opposed edges extending in a second direction which intersects said first direction, said bonding pads being arranged in said first direction to form a row of bonding pads;
- (2) a substrate, formed by glass fibers impregnated with epoxy resin, having a first surface, a second surface opposite to said first surface, electrode pads formed on said second surface and a slit passing through said substrate from said first surface to said second surface and extending in said first direction, said semiconductor pellet being disposed on said first surface of said substrate such that said main surface of said semiconductor pellet is faced to said first surface of said substrate and said row of bonding pads is arranged in said slit in a plane view, said electrode pads including first electrode pads arranged at one side of said slit and second electrode pads arranged at the other side of said slit in said second direction;
- (3) bonding wires, each extending from one of said bonding pads of said semiconductor pellet to pass through said slit from said first surface of the substrate to the second surface of the substrate to electrically connecting said electrode pads of said substrate with said bonding pads of said semiconductor pellet via said slit, said bonding wires including first bonding wires connected to said first electrode pads and second bonding wires connected to said second electrode pads;

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- (4) bump electrodes being disposed on said second surface of said substrate and being electrically connected to said electrode pads of said substrate, said bump electrodes including first bump electrodes electrically connected to said first electrode pads and arranged at said one side of said slit and second bump electrodes electrically connected to said second electrode pads and arranged at the other side of said slit, said first and second bump electrodes being arranged to overlap with said semiconductor pellet in said plane view respectively; and
- (5) a resin sealing body sealing said bonding wires and said main surface of said semiconductor pellet exposed from said slit.

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27. A semiconductor device according to claim 26, wherein said row of bonding pads is disposed at a substantially central area between said first pair of opposed edges of said semiconductor pellet.

28. A semiconductor device according to claim 26, wherein said semiconductor pellet has a rectangular shape, and wherein said first pair of opposed edges are corresponding to a pair of longer edges and said second pair of opposed edges are corresponding to a pair of shorter edges.

29. A semiconductor device according to claim 26, wherein said slit is tapered so that opening on said second surface of substrate is greater than opening on said first surface of said substrate.

30. A semiconductor device according to claim 26, wherein said bump electrodes are formed of a Pb-Sn alloy.

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32. A semiconductor device according to claim 26, wherein said bonding wires are formed of gold.

33. A semiconductor device according to claim 32, wherein said bonding wires are connected to said bonding pads and said electrode pads by a bonding method that utilizes ultrasonic vibration in combination with thermo-compression.

34. A semiconductor device according to claim 26, wherein said substrate has land portions and conductors formed between said land portions and said electrode pads, wherein width of each of said land portions is larger than that of each of said conductors, wherein said land portions, said conductors and said electrode pads are integrally formed with one another on said second surface, and wherein said bump electrodes are arranged on said land portions.

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15. A semiconductor device according to claim 14, wherein said substrate is formed of a single layer structure that has conductors arranged only on said second surface of said substrate.

16. A semiconductor device according to claim 26, wherein a pitch of said electrodes pads in said first direction is greater than a pitch of said bonding pads in said first direction.

17. A semiconductor device according to claim 26, wherein said substrate has a periphery which protrudes outwardly from said first and second pairs of opposed edges of said semiconductor pellet, wherein said first surface of said periphery of said substrate and said semiconductor pellet are sealed with a resin sealing body, and wherein a rear surface of said semiconductor pellet opposite to said main surface is exposed from said resin sealing body.

18. A semiconductor device according to claim 17, wherein said bump electrodes are arranged on said second surface of said substrate that overlap with said semiconductor pellet in said plane view and on said second surface of substrate at said periphery.

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39.-90. (Canceled)

91. (New) A semiconductor device comprising:

- (1) a semiconductor pellet of a quadrilateral shape having bonding pads formed in a main surface thereof, said semiconductor pellet having a first pair of opposed edges extending in a first direction and a second pair of opposed edges extending in a second direction which intersects said first direction, said bonding pads being arranged in said first direction to form a row of bonding pads;
- (2) a substrate, formed of a glass fiber impregnated with resin, having a first surface, a second surface opposite to said first surface, electrode pads formed on said second surface and a slit passing through said substrate from said first surface to said second surface and extending in said first direction, said semiconductor pellet being disposed on said first surface of said substrate such that said main surface of said semiconductor pellet is faced to said first surface of said substrate and said row of binding pads is arranged in said slit in a plane view, said electrode pads including first electrode pads arranged at one side of said slit and second electrode pads arranged at the other side of said slit in said second direction;
- (3) bonding wires electrically connecting said electrode pads of said substrate with said bonding pads of said semiconductor pellet via said slit, said bonding



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wires including first bonding wires connected to said first electrode pads and second bonding wires connected to said second electrode pads;

- (4) bump electrodes being disposed on said second surface of said substrate and being electrically connected to said electrode pads of said substrate, said bump electrodes including first bump electrodes electrically connected to said first electrode pads and arranged at said one side of said slit and second bump electrodes electrically connected to said second electrode pads and arranged at the other side of said slit, said first and second bump electrodes being arranged to overlap with said semiconductor pellet in said plane view respectively; and
- (5) a resin sealing body sealing said bonding wires and said main surface of said semiconductor pellet exposed from said slit.

92. (New) A semiconductor device according to claim 91, wherein said row of bonding pads is disposed at a substantially central area between said first pair of opposed edges of said semiconductor pellet.

93. (New) A semiconductor device according to claim 92, wherein said semiconductor pellet has a rectangular shape, and wherein said first pair of opposed edges are corresponding to a pair of longer edges and said second pair of opposed edges are corresponding to a pair of shorter edges.

94. (New) A semiconductor device according to claim 91, wherein said slit is tapered so that opening on said second surface of substrate is greater than opening on said first surface of said substrate.

95. (New) A semiconductor device according to claim 91, wherein said bump electrodes are formed of a Pb-Sn alloy.

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96. (New) A semiconductor device comprising:

- (1) a semiconductor pellet of a quadrilateral shape having bonding pads formed in a main surface thereof, said semiconductor pellet having a first pair of opposed edges extending in a first direction and a second pair of opposed edges extending in a second direction which intersects said first direction, said bonding pads being arranged in said first direction;
- (2) a substrate, formed of a glass fiber impregnated with resin, having a first surface, a second surface opposite to said first surface, electrode pads formed on said second surface and a slit passing through said substrate from said first surface to said second surface and extending in said first direction, said semiconductor pellet being disposed on said first surface of said substrate such that said main surface of said semiconductor pellet is faced to said first surface of said substrate and said bonding pads are arranged in said slit in a plane view, said electrode pads including first electrode pads arranged at one side of said slit and second electrode pads arranged at the other side of said slit in said second direction;

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- (3) bonding wires electrically connecting said electrode pads of said substrate with said bonding pads of said semiconductor pellet via said slit, said bonding wires including first bonding wires connected to said first electrode pads and second bonding wires connected to said second electrode pads;
- (4) bump electrodes being disposed on said second surface of said substrate and being electrically connected to said electrode pads of said substrate, said bump electrodes including first bump electrodes electrically connected to said first electrode pads and arranged at said one side of said slit and second bump electrodes electrically connected to said second electrode pads and arranged at the other side of said slit, said first and second bump electrodes being arranged to overlap with said semiconductor pellet in said plane view respectively; and
- (5) a resin sealing body sealing said bonding wires and said main surface of said semiconductor pellet exposed from said slit.
97. (New) A semiconductor device according to claim 96, wherein said bonding pads are disposed at a substantially central area between said first pair of opposed edges of said semiconductor pellet.
98. (New) A semiconductor device according to claim 97, wherein said semiconductor pellet has a rectangular shape, and wherein said first pair of opposed edges are corresponding to a pair of longer edges and said second pair of opposed edges are corresponding to a pair of shorter edges.

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99. (New) A semiconductor device according to claim 96, wherein said slit is tapered so that opening on said second surface of substrate is greater than opening on said first surface of said substrate.

100. (New) A semiconductor device according to claim 96, wherein said bump electrodes are formed of a Pb-Sn alloy.

101. (New) A semiconductor device according to claim 96, wherein at least some of said bonding pads extend in said first direction to form a row of bonding pads.

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